

MEMORY MODULE

FLASH NOR QSPI 3DFS512M04VS2722

512 Mbit QSPI FLASH NOR, based on 128M

3DFS512M04VS2722



GENERAL DESCRIPTION

The 3DFS512M04VS2722 is a Quad SPI Flash NOR memory organized in 4 banks of 128 Mbit each with distinct chip enable CEn# (n from 0 to 3) controls. It requires only a single 3.0 V power supply for both read and write functions.

Thanks to dual SPI and quad SPI interfaces, and Fast Read mode feature, our serial NOR Flash memory can achieve high throughput (up to 133 MHz), which makes it suitable for high speed circuit applications. It is highly suitable for code storage in embedded systems

Thanks to the SPI interface, the 3DFS512M04VS2722 achieve s very low pin count. It is packaged in a 18 pin SOP.

KEY FEATURES

Single Power Supply operation: 3.0 V

Supports standard SPI, Fast, Dual, QPI, SPI DTR, and Dual SPI DTR I/O

50 MHz in Normal mode and 133 MHz in Fast Read mode

More than 100,000 erase/program cycles

More than 20-year data retention

Program 1 to 256 bytes per page

Program/Erase Suspend & Resume

Low Instruction Overhead Operations

Continuous Read 8/16/32/64-byte burst

Selectable burst length

QPI for reduced instruction overhead

Available Temperature Range:

0°C to +70°C

-40°C to +85°C

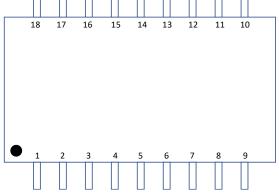
-55°C to +105°C

Available with screening options for high reliability application up to grade S

ITAR free

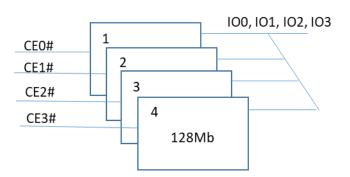


PIN ASSIGNMENT (top view)



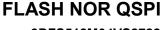
1	CE1#	10	SI/IO0
2	RFU	11	SCK
3	NC	12	HOLD#/IO3
4	GND	13	VCC
5	RFU	14	CE2#
6	CE0#	15	RFU
7	SO/IO1	16	RFU
8	WP#/IO2	17	CE3#
9	GND	18	VCC

FUNCTIONAL BLOCK DIAGRAM



All other signals are common to all memories

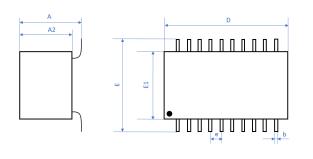
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MECHANICAL DRAWING



Dimensions (mm)

	MIN	MAX
А	6.95	7.85
A2	5.85	6.45
D	13.80	14.20
E	15.70	16.10
E1	10.90	11.10
b	0.	35
е	1.	27

Max. weight: 2.40 g

DC Operating Conditions and Characteristics

Parameter	Symbol	Min	Мах	Unit
Supply Voltage	V _{CC}	2.3	3.6	V
Input logic High Voltage	V _{IH}	$0.7 \text{ x V}_{\text{CC}}$	V _{CC} + 0.3	V
Input logic Low Voltage	V _{IL}	-0.3	$0.3 \text{ x V}_{\text{CC}}$	V
Output logic High Voltage	V _{OH}	V _{CC} - 0.2	_	V
Output logic Low Voltage	V _{OL}	-	0.2	V

Absolute Maximum Ratings

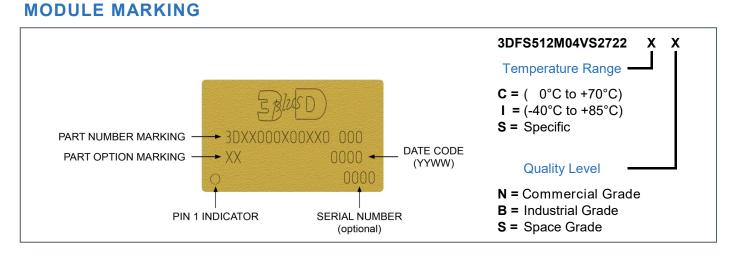
Parameter	Symbol	Value	Unit
Input voltage relative to $V_{\mbox{\scriptsize SS}}$	V _T	-0.5 to V _{CC} + 0.3	V
Storage temperature	T _{STG}	-65 to +150	°C

DC Characteristics

Parameter	Symbol	Value	Unit
V _{CC} active read current	I _{CC1}	14	mA
V _{CC} active write current	I _{CC2}	25	mA

Note: Permanent device damage may occur if "Absolute maximum ratings" are exceeded. Functional operation should be restricted to recommended operating condition.

Exposure to higher than recommended voltage for extended periods of time could affect device reliability.



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